

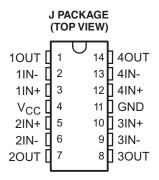
QUADRUPLE OPERATIONAL AMPLIFIER

Check for Samples: LM124-SP, LM124A-SP

FEATURES

- QML-V Qualified, SMD 5962-7704301VCA, 5962-9950403VCA and 5962-9950403V9B
- Rad-Tolerant: 50 kRad (Si) TID (5962-9950403VCA and 5962-9950403V9B) (1)
 - TID Dose Rate = 0.01 rad/sec (Si)
- Wide Supply Ranges
 - Single Supply: 3 V to 32 V
 - Dual Supplies: ±1.5 V to ±16 V
- Low Supply-Current Drain Independent of Supply Voltage: 0.8 mA (Typ)
- Low Input Bias and Offset Parameters
 - Input Offset Voltage: 1 mV Typ
 Input Offset Current: 2 nA Typ
 Input Bias Current: 30 nA Typ
- Common-Mode Input Voltage Range Includes Ground, Allowing Direct Sensing Near Ground
- (1) Radiation tolerance is a typical value based upon initial device qualification with dose rate = 0.01 rad/sec. Radiation lot acceptance testing is available - contact factory for details.

- Differential Input Voltage Range Equal to Maximum-Rated Supply Voltage: ±32 V
- Open-Loop Differential Voltage Amplification: 100 V/mV Typ
- Internal Frequency Compensation



DESCRIPTION/ORDERING INFORMATION

These devices consist of four independent high-gain frequency-compensated operational amplifiers that are designed specifically to operate from a single supply over a wide range of voltages. Operation from split supplies also is possible if the difference between the two supplies is 3 V to 32 V, and V_{CC} is at least 1.5 V more positive than the input common-mode voltage. The low supply-current drain is independent of the magnitude of the supply voltage.

Applications include transducer amplifiers, dc amplification blocks, and all the conventional operational-amplifier circuits that now can be more easily implemented in single-supply-voltage systems. For example, the LM124 can be operated directly from the standard 5-V supply that is used in digital systems and provides the required interface electronics, without requiring additional ±15-V supplies.

Table 1. ORDERING INFORMATION(1)

T _A	V _{IO} max AT 25°C	MAX V _{CC}	PACKAGE ⁽²⁾	ORDERA	BLE PART NUMBER	TOP-SIDE MARKING
	5 mV	30 V	- J	LM124	5962-7704301VCA	5962-7704301VCA
-55°C to 125°C	3 mV	30 V		LM124A	5962-9950403VCA ⁽³⁾	5962-9950403VCA
	3 mV	30 V	KGD	596	2-9950403V9B ⁽³⁾	N/A

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (3) Radiation tolerant



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



BARE DIE INFORMATION

DIE THICKNESS	BACKSIDE FINISH Silicon with backgrind	BACKSIDE POTENTIAL	BON PAD METALLIZATION COMPOSITION	BOND PAD THICKNESS
15 mils	Silicon with backgrind	Floating	AlCu (0.5%)	0.055 mils

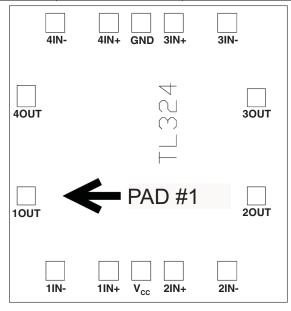
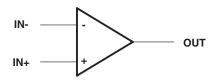


Table 2. Bond Pad Coordinates in Microns

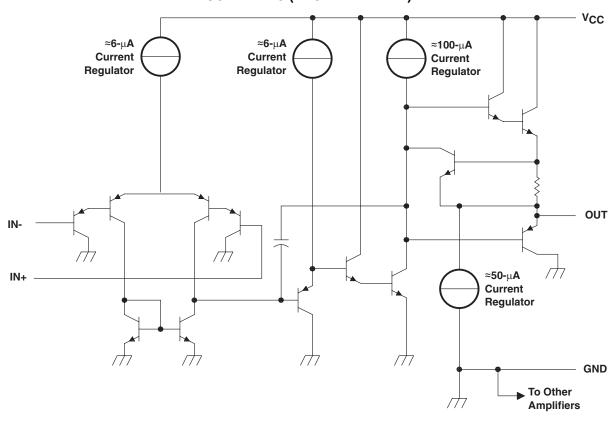
DISCRIPTION	PAD NUMBER	Xmin	Ymin	Xmax	Ymax
1OUT	1	426.72	1249.68	523.24	1346.20
1IN-	2	25.40	1093.47	127	1192.53
1IN+	3	25.40	808.99	127	910.59
V _{CC}	4	25.40	635	127	734.06
2IN+	5	25.40	462.28	127	563.88
2IN-	6	25.40	177.80	127	279.40
2OUT	7	426.72	25.40	523.24	121.92
3OUT	8	949.96	25.40	1046.48	121.92
3IN-	9	1346.20	177.80	1447.80	279.40
3IN+	10	1346.20	462.28	1447.80	563.88
GND	11	1346.20	635	1447.80	736.60
4IN+	12	1346.20	807.72	1447.80	909.32
4IN-	13	1346.20	1092.2	1447.80	1193.80
4OUT	14	949.96	1249.68	1046.48	1346.20



SYMBOL (EACH COMPARATOR)



SCHEMATIC (EACH AMPLIFIER)



COMPONENT COUNT (total device)							
Epi-FET	1						
Transistors	95						
Diodes	4						
Resistors	11						
Capacitors	4						



ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾			±16 or 32	V
V_{ID}	Differential input voltage (3)			±32	V
V_{I}	Input voltage range (either input)				
	Duration of output short circuit to ground (4)	uration of output short circuit to ground (4)			
θ_{JC}	Package thermal impedance, junction to case (5) (6)	J package		15.05	°C/W
T_J	Operating virtual-junction temperature			150	°C
	Lead temperature 1,6 mm (1/16 in) from case for 60 s			300	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values, except differential voltages, are with respect to network ground.

Differential voltages are at IN+ with respect to IN-.

Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.

Maximum power dissipation is a function of T_J (max), θ_{JC} , and T_C . The maximum allowable power dissipation at any allowable case (5) temperature is $P_D = (T_J (max) - T_C)/\theta_{JC}$. Operating at the absolute maximum T_J of 150°C can affect reliability. (6) The package thermal impedance is calculated in accordance with MIL-STD-883.



ELECTRICAL CHARACTERISTICS FOR LM124

at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS ⁽¹⁾	T _A ⁽²⁾	MIN	TYP ⁽³⁾	MAX	UNIT	
		$V_{CC} = 5 \text{ V to M}$	AX,	25°C		3	5		
V _{IO}	Input offset voltage	$V_{IC} = V_{ICR} \text{ min,}$ $V_{O} = 1.4 \text{ V}$		Full range			7	mV	
	Input offset current	V _O = 1.4 V		25°C		2	30	nA	
I _{IO}	input onset current	v _O = 1.4 v		Full range			100	ПА	
	Input bias current	V _O = 1.4 V		25°C		-20	-150	nA	
I _{IB}	input bias current	V _O = 1.4 V		Full range			-300	IIA	
V	Common-mode input-voltage	$V_{CC} = 5 \text{ V to M}$	^	25°C	$V_{CC} - 1.5$			V	
V _{ICR}	range	V _{CC} = 5 V to W	47	Full range	$V_{CC} - 2$			V	
		$R_L = 2 k\Omega$		25°C	$V_{CC} - 1.5$				
\/	High-level output voltage	$R_L = 10 \text{ k}\Omega$		25°C				V	
V _{OH}	nigh-level output voltage	\/ - NAAY	$R_L = 2 k\Omega$	Full range	26			V	
		$V_{CC} = MAX$	$R_L \ge 10 \text{ k}\Omega$	Full range	27	28			
V_{OL}	Low-level output voltage	$R_L \le 10 \text{ k}\Omega$		Full range		5	20	mV	
	Large-signal differential-voltage	V _{CC} = 15 V, V _O	= 1 V to 11 V,	25°C	50	100		V/mV	
A_{VD}	amplification	R _L ≥ 2 kΩ			25			V/IIIV	
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min$		25°C	70	80		dB	
k _{SVR}	Supply-voltage rejection ratio $(\Delta V_{CC}/\Delta V_{IO})$			25°C	65	100		dB	
V _{O1} / V _{O2}	Crosstalk attenuation	f = 1 kHz to 20	kHz	25°C		120		dB	
		$V_{CC} = 15 V$,		25°C	-20	-30	-60		
		$V_{ID} = 1 V,$ $V_{O} = 0$	Source	Full range	-10				
Io	Output current	$V_{CC} = 15 \text{ V},$		25°C	10	20		mA	
		$V_{ID} = -1 \text{ V},$ $V_{O} = 15 \text{ V}$	Sink	Full range	5				
		$V_{ID} = -1 V$,	V _O = 200 mV	25°C	12	30			
I _{OS}	Short-circuit output current	V _{CC} at 5 V, GND at −5 V,	V _O = 0 V	25°C		±40	±60		
	Cumply gurrant	$V_O = 2.5 \text{ V}$, No load		Full range		0.7	1.2		
I _{CC}	Supply current (four amplifiers)	$V_{CC} = MAX,$ $V_{O} = 0.5 V_{CC},$	No load	Full range		1.4	3	mA	

⁽¹⁾ All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 30 V. Full range is −55°C to 125°C for LM124.

⁽³⁾ All typical values are at $T_A = 25$ °C.



ELECTRICAL CHARACTERISTICS FOR LM124A

at specified free-air temperature, $V_{cc} = 5 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS ⁽¹⁾	T _A ⁽²⁾	MIN TYP ⁽³⁾) MAX	UNIT	
		$+V_{CC} = 30 \text{ V},$ $-V_{CC} = \text{GND},$	25°C		±3	mV	
		$V_{CM} = 35 \text{ V}$	Full range		±5	IIIV	
		$+V_{CC} = 2 V,$	25°C		±3		
,		$-V_{CC} = -28 \text{ V},$ $V_{CM} = -13 \text{ V}$	Full range		±5	mV	
/ ₁₀	Input offset voltage	+V _{CC} = 5 V,	25°C		±3		
		$-V_{CC} = GND,$ $V_{CM} = 1.4 V$	Full range		±5	mV	
		+V _{CC} = 2.5 V,	25°C		±3		
		$-V_{CC} = -2.5 \text{ V},$ $V_{CM} = -1.1 \text{ V}$	Full range		±5	mV	
		+V _{CC} = 30 V,	25°C		±10		
		$-V_{CC} = GND,$ $V_{CM} = 15 V$	Full range		±30	nA	
		+V _{CC} = 2 V,	25°C		±10		
		$-V_{CC} = -28 \text{ V},$ $V_{CM} = -13 \text{ V}$	Full range		±30	nA	
0	Input offset current	+V _{CC} = 5 V,	25°C		±10	nA	
		$-V_{CC} = GND,$ $V_{CM} = 1.4 V$	Full range		±30		
		+V _{CC} = 2.5 V,	25°C		±10	A	
		$-V_{CC} = -2.5 \text{ V},$ $V_{CM} = -1.1 \text{ V}$	Full range		±30	nA	
		+V _{CC} = 30 V,	25°C	-85	0.1		
		$-V_{CC} = GND,$ $V_{CM} = 15 V$	Full range	-100	0.1	nA	
		+V _{CC} = 2 V,	25°C	-50	0.1		
		$-V_{CC} = -28 \text{ V},$ $V_{CM} = -13 \text{ V}$	Full range	-100	0.1	nA	
-I _{IB}	Input bias current	+V _{CC} = 5 V,	25°C	-50	0.1	nA	
		$-V_{CC} = GND,$ $V_{CM} = 1.4 \text{ V}$	Full range	-100	0.1		
		+V _{CC} = 2.5 V,	25°C	-50	0.1		
		$-V_{CC} = -2.5 \text{ V},$ $V_{CM} = -1.1 \text{ V}$	Full range	-100	0.1	nA	
		+V _{CC} = 30 V,	25°C	-85	0.1		
		$-V_{CC} = GND,$ $V_{CM} = 15 V$	Full range	-100	0.1	nA	
		$+V_{CC} = 2 \text{ V},$	25°C	-50	0.1		
		$-V_{CC} = -28 \text{ V},$ $V_{CM} = -13 \text{ V}$	Full range	-100	0.1	nA	
I _{IB}	Input bias current	+V _{CC} = 5 V,	25°C	-50	0.1		
		$-V_{CC} = GND,$ $V_{CM} = -1.4 \text{ V}$	Full range	-100	0.1	nA	
		+V _{CC} = 2.5 V,	25°C	-50	0.1		
		$-V_{CC} = -2.5 \text{ V},$ $V_{CM} = -1.1 \text{ V}$	Full range	-100	0.1	nA	
SRR	Power supply rejection ratio	-V _{CC} = GND, V _{CM} = 1.4 V 5 V = VCC = 30 V	Full range	-100	100	μV/V	
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR} min	Full range	76		dB	
os	Short-circuit output current	+V _{CC} = 30 V, -V _{CC} = GND, V _{OUT} = 25 V	Full range	-70		mA	

All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 30 V. Full range is -55°C to 125°C for LM124A.

⁽³⁾ All typical values are at $T_A = 25$ °C.



ELECTRICAL CHARACTERISTICS FOR LM124A (continued)

at specified free-air temperature, $V_{CC} = 5 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS ⁽¹⁾	T _A ⁽²⁾	MIN	TYP ⁽³⁾ MAX	UNIT	
I _{CC}	Power supply current	$+V_{CC} = 30 \text{ V},$	125°C		3	mA	
	1 ower supply surrent	$-V_{CC} = GND,$	-55°C		4	1117 (
ΔV _{IO} / ΔΤ	Input offset voltage temperature sensitivity (4)	$+V_{CC} = 5 \text{ V},$ $-V_{CC} = \text{GND},$ $V_{CM} = 1.4 \text{ V}$	125°C, -55°C	-30	30	μV/°C	
ΔI _{IO} /	Input offset current temperature	+V _{CC} = 5 V,	125°C	-400	400		
ΔΤ	sensitivity ⁽⁴⁾	-V _{CC} = GND, V _{CM} = 1.4 V	-55°C	-700	700	pA/°C	
		$+V_{CC} = 30 \text{ V},$ $-V_{CC} = \text{GND},$ $R_L = 10 \text{ k}\Omega$	Full range		35	mV	
V _{OL}	Low-level output voltage	$+V_{CC} = 30 \text{ V},$ $-V_{CC} = \text{GND},$ $I_{OL} = 5 \text{ mA}$	Full range		1.5	٧	
		$+V_{CC} = 4.5 \text{ V},$ $-V_{CC} = \text{GND},$ $I_{OL} = 2 \mu\text{A}$	Full range		0.4		
V	High-level output voltage	$+V_{CC} = 30 \text{ V},$ $-V_{CC} = \text{GND},$ $I_{OH} = 10 \text{ mA}$	Full range	27		V	
V _{OH}	riigii-level output voltage	$+V_{CC} = 4.5 \text{ V},$ $-V_{CC} = \text{GND},$ $I_{OH} = -10 \text{ mA}$	Full range	2.4		V	
		$+V_{CC} = 30 \text{ V},$	25°C	50			
1	Valta na main	$-V_{CC} = GND,$ $1 \ V \le V_{OUT} \le 26 \ V$ $R_{L} = 10 \ k\Omega$	Full range	25		V/mV	
A _{VS+}	Voltage gain	$+V_{CC} = 30 \text{ V},$	25°C	50		v/mv	
		$-V_{CC} = GND,$ $5 \text{ V} \leq V_{OUT} \leq 20 \text{ V}$ $R_{L} = 2 \text{ k}\Omega$	Full range	25			
۸	Voltago gaio	$\begin{aligned} +V_{CC} &= 5 \text{ V}, \\ -V_{CC} &= \text{GND}, \\ 1 \text{ V} &\leq V_{OUT} \leq 2.5 \text{ V} \\ R_L &= 10 \text{ k}\Omega \end{aligned}$	Full range	10		V/mV	
A _{VS}	Voltage gain	$\begin{aligned} +V_{CC} &= 5 \text{ V,} \\ -V_{CC} &= \text{GND,} \\ 5 \text{ V} &\leq V_{OUT} \leq 2.5 \text{ V} \\ R_L &= 2 \text{ k}\Omega \end{aligned}$	Full range	10		V/IIIV	
/	Mariana	$\begin{aligned} +V_{CC} &= 30 \text{ V}, \\ -V_{CC} &= GND, \\ V_{OUT} &= 30 \text{ V} \\ R_L &= 10 k\Omega \end{aligned}$	Full range	27		V	
+V _{OP}	Maximum output voltage swing	$\begin{aligned} + V_{CC} &= 30 \text{ V}, \\ - V_{CC} &= \text{GND}, \\ V_{OUT} &= 30 \text{ V} \\ R_L &= 2 \text{ k}\Omega \end{aligned}$	Full range	26		V	
TR(t _r)	Transient response: rise time (4)	+V _{CC} = 30 V, -V _{CC} = GND	Full range		1	μS	
SR+	Slew rate: rise ⁽⁴⁾	+V _{CC} = 30 V, -V _{CC} = GND	Full range	0.1		V/μs	
SR-	Slew rate: fall ⁽⁴⁾	+V _{CC} = 30 V, -V _{CC} = GND	Full range	0.1		V/μs	
NI(BB)	Noise broadband ⁽⁴⁾	+V _{CC} = 15 V, -V _{CC} = -15 V, BW = 10 Hz to 5 kHz	25°C		15	μV/rms	

⁽⁴⁾ Parameter characterized over temperature, but not production tested.



ELECTRICAL CHARACTERISTICS FOR LM124A (continued)

at specified free-air temperature, $V_{CC} = 5 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS ⁽¹⁾	T _A ⁽²⁾	MIN	TYP ⁽³⁾	MAX	UNIT
NI(PC)	Noise popcorn ⁽⁵⁾	+VCC = 15 V, -VCC = -15 V, R_S = 20 kΩ, BW = 10 Hz to 5 kHz	25°C			50	μV/peak
cs	Channel separation	$\begin{aligned} + V_{CC} &= 30 \text{ V}, \\ - V_{CC} &= \text{GND}, \\ R_L &= 2 \text{ k}\Omega \end{aligned}$	25°C	80			dB
	ŕ	$\begin{aligned} R_L &= 2 \ k\Omega, \\ V_{IN} &= 1 \ V \ \text{and} \ 16 \ V \end{aligned}$	25°C	80			

⁽⁵⁾ Parameter characterized over temperature, but not production tested.

OPERATING CONDITIONS

 $V_{CC} = \pm 15 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
SR	Slew rate at unity gain	$R_L = 1 \text{ M}\Omega$, $C_L = 30 \text{ pF}$, $V_I = \pm 10 \text{ V}$ (see Figure 1)	0.5	V/μs
B ₁	Unity-gain bandwidth	$R_L = 1 \text{ M}\Omega$, $C_L = 20 \text{ pF}$ (see Figure 1)	1.2	MHz
V_n	Equivalent input noise voltage	$R_S = 100 \Omega$, $V_I = 0 V$, $f = 1 kHz$ (see Figure 2)	35	nV/√ Hz

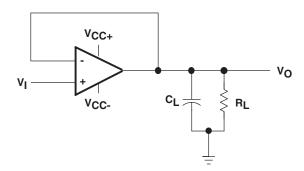


Figure 1. Unity-Gain Amplifier

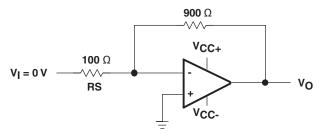


Figure 2. Noise-Test Circuit



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-7704301VCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-7704301VC A LM124JQMLV	Samples
5962-9950403V9B	ACTIVE	XCEPT	KGD	0	100	RoHS & Green	Call TI	N / A for Pkg Type	-55 to 125		Samples
5962-9950403VCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950403VC A LM124AJQMLV	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

PACKAGE OPTION ADDENDUM

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF LM124-SP:

Catalog: LM124

Military : LM124M

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Device Package Name		Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)	
5962-9950403VCA	J	CDIP	14	25	506.98	15.24	13440	NA	

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



NOTES:

- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



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